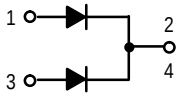
SWITCHMODE™ Power Rectifier

. . . using the Schottky Barrier principle with a platinum barrier metal. These state–of–the–art devices have the following features:

- Dual Diode Construction — Terminals 1 and 3 may be Connected for Parallel Operation at Full Rating
- Guardring for Stress Protection
- Low Forward Voltage
- 150°C Operating Junction Temperature
- Guaranteed Reverse Avalanche

Mechanical Characteristics:

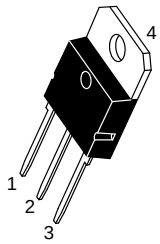
- Case: Epoxy, Molded
- Weight: 4.3 grams (approximately)
- Finish: All External Surfaces Corrosion Resistant and Terminal Leads are Readily Solderable
- Lead Temperature for Soldering Purposes: 260°C Max. for 10 Seconds
- Shipped 30 units per plastic tube
- Marking: B3045



MBR3045PT

Motorola Preferred Device

SCHOTTKY BARRIER RECTIFIER 30 AMPERES 45 VOLTS



CASE 340D–02

MAXIMUM RATINGS

Rating		Symbol	Maximum	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage		V_{RRM} V_{RWM} V_R	45	Volts
Average Rectified Forward Current (Rated V_R) T_C = 105°C	Per Device Per Diode	$I_{F(AV)}$	30 15	Amps
Peak Repetitive Forward Current, Per Diode (Rated V_R, Square Wave, 20 kHz)		I_{FRM}	30	Amps
Nonrepetitive Peak Surge Current (Surge applied at rated load conditions halfwave, single phase, 60 Hz)		I_{FSM}	200	Amps
Peak Repetitive Reverse Current, Per Diode (2.0 μs, 1.0 kHz) See Figure 6		I_{RRM}	2.0	Amps
Operating Junction Temperature		T_J	– 65 to +150	°C
Storage Temperature		T_{stg}	– 65 to +175	°C
Peak Surge Junction Temperature (Forward Current Applied)		$T_{J(pk)}$	175	°C
Voltage Rate of Change (Rated V_R)		dv/dt	10000	V/μs

THERMAL CHARACTERISTICS PER DIODE

Thermal Resistance, Junction to Case	$R_{\theta JC}$	1.4	°C/W
Thermal Resistance, Junction to Ambient	$R_{\theta JA}$	40	°C/W

ELECTRICAL CHARACTERISTICS PER DIODE

Instantaneous Forward Voltage (1) (i_F = 20 Amps, T_C = 125°C) (i_F = 30 Amps, T_C = 125°C) (i_F = 30 Amps, T_C = 25°C)	v_F	 0.60 0.72 0.76	Volts
Instantaneous Reverse Current (1) (Rated dc Voltage, T_C = 125°C) (Rated dc Voltage, T_C = 25°C)	i_R	 100 1.0	mA

(1) Pulse Test: Pulse Width = 300 μs, Duty Cycle ≤ 2.0%.

SWITCHMODE is a trademark of Motorola, Inc.
Preferred devices are Motorola recommended choices for future use and best overall value.

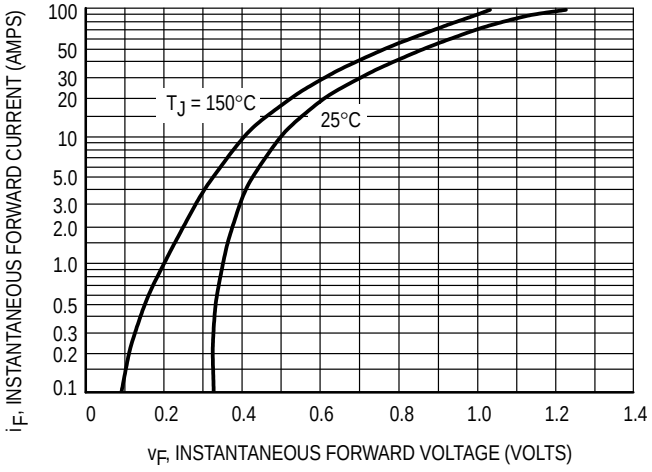


Figure 1. Typical Forward Voltage

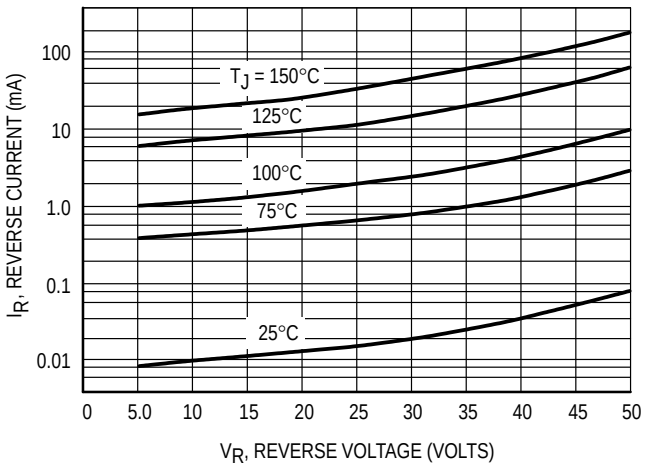


Figure 2. Typical Reverse Current

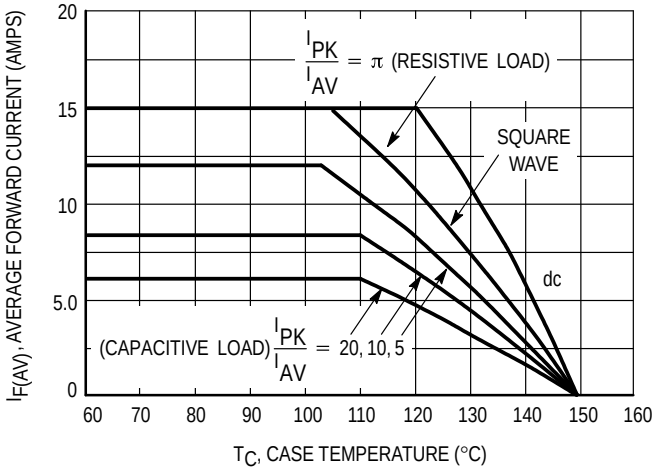


Figure 3. Current Derating (Per Leg)

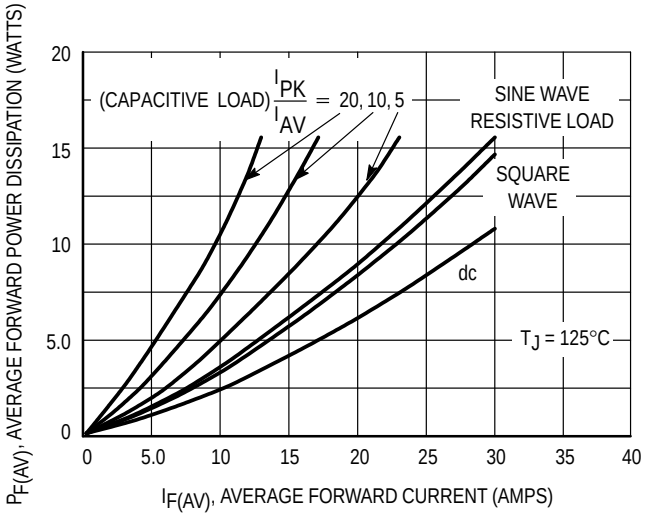


Figure 4. Forward Power Dissipation (Per Leg)

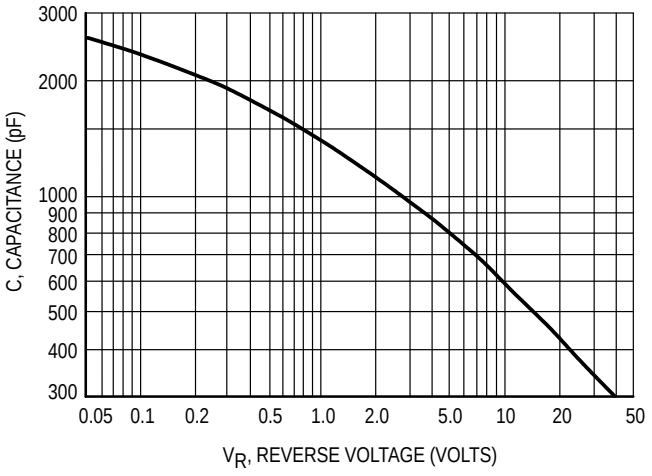


Figure 5. Capacitance

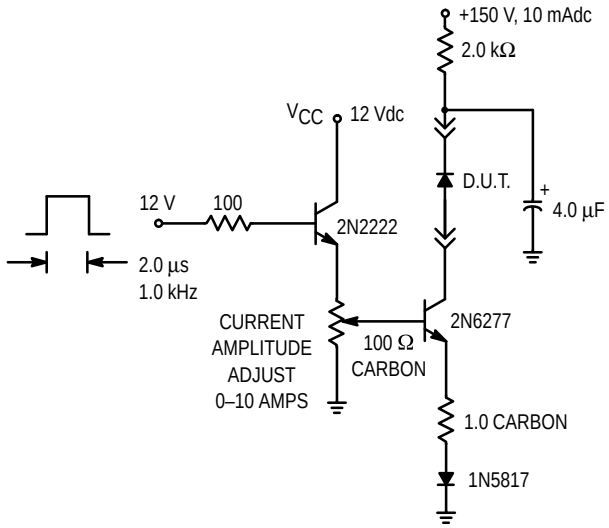
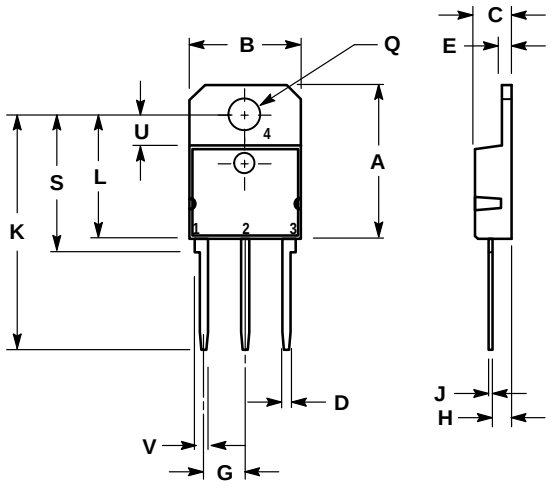


Figure 6. Test Circuit for Repetitive Reverse Current

PACKAGE DIMENSIONS



NOTES:
1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: MILLIMETER.

	MILLIMETERS		INCHES	
DIM	MIN	MAX	MIN	MAX
A	——	20.35	——	0.801
B	14.70	15.20	0.579	0.598
C	4.70	4.90	0.185	0.193
D	1.10	1.30	0.043	0.051
E	1.17	1.37	0.046	0.054
G	5.40	5.55	0.213	0.219
H	2.00	3.00	0.079	0.118
J	0.50	0.78	0.020	0.031
K	31.00 REF		1.220 REF	
L	——	16.20	——	0.638
Q	4.00	4.10	0.158	0.161
S	17.80	18.20	0.701	0.717
U	4.00 REF		0.157 REF	
V	1.75 REF		0.069	

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ISSUE B

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